Diode Semiconductor Device - Page 1 of 1



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Inclos	sure Material:
Glass	and metal
Overa	II Length:
0.335	inches
Termi	nal Length:
1.000	inches
Overa	II Diameter:
Betwe	en 0.360 inches and 0.400 inches
Moun	ting Method:
Termi	nal
Featu	res Provided:
Herme	etically sealed case
Semio	conductor Material:
Silicor	1
Voltag	ge Rating In Volts Per Characteristic:
600.0	reverse voltage, peak
Curre	nt Rating Per Characteristic:
1.60 a	mperes forward current, average absolute
Maxin	num Operating Tempurature Per Measurement Point:
175.0	degrees celsius junction
Termi	nal Type And Quantity:
1 ferru	Ile and 1 uninsulated wire lead
Speci	fication Data:
80131	-release2114 professional/industrial association specification
Shelf	Life:
N/a	
Unit C	Of Measure:
Demil	itarization:
No	
Fiig:	
A110a	a0